

## Band Switching Diodes - Dual, Series in SOT-323

### Description

The main purpose of the BA892V-04W is the Band Switching. Biased with a DC forward current for signals at frequencies over 100 MHz up to 3 GHz this diode behaves like a current controlled resistor and not as a diode any more.

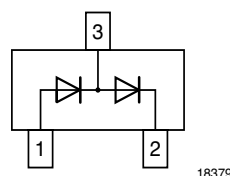
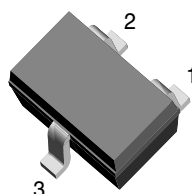
Depending on the forward current the forward resistance  $r_f$  can be switched far below  $1\ \Omega$ , so that the Switch is closed.

To open the Switch, the BA892V-04W has to be driven in the reverse mode where the BA892V-04W behaves like a small capacitor with high isolation.

So typical applications for this Band Switching Diode are mobile and TV-applications.

### Features

- Low forward resistance
- Small reverse capacitance
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



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### Applications

Band switching up to 3 GHz  
Low loss band-switching in TV/VTR tuners

### Mechanical Data

**Case:** SOT-323 Plastic case

**Weight:** approx. 6.0 mg

**Packaging Codes/Options:**

GS08 / 3 k per 7" reel (8 mm tape), 3 k/box

### Parts Table

Part	Ordering code	Marking	Remarks
BA892V-04W	BA892V-04W-GS08	AW4	Tape and Reel

### Absolute Maximum Ratings

$T_{amb} = 25\ ^\circ\text{C}$ , unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		$V_R$	35	V
Forward current		$I_F$	100	mA
Junction temperature		$T_j$	150	$^\circ\text{C}$
Storage temperature range		$T_{stg}$	-55 to +150	$^\circ\text{C}$

### Thermal Characteristics

$T_{amb} = 25\ ^\circ\text{C}$ , unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Junction soldering point		$R_{thJS}$	100	K/W

## Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Reverse voltage	$I_R = 10\text{ }\mu\text{A}$	$V_R$	35			V
Reverse current	$V_R = 20\text{ V}$	$I_R$			20	nA
Forward voltage	$I_F = 100\text{ mA}$	$V_F$			1.1	V
Diode capacitance	$f = 1\text{ MHz}$ , $V_R = 0$	$C_D$		1.1		pF
	$f = 1\text{ MHz}$ , $V_R = 1\text{ V}$	$C_D$		0.9	1.2	pF
	$f = 1\text{ MHz}$ , $V_R = 3\text{ V}$	$C_D$		0.85	1.1	pF
Forward resistance	$f = 100\text{ MHz}$ , $I_F = 1\text{ mA}$	$r_f$		0.6		$\Omega$
	$f = 100\text{ MHz}$ , $I_F = 3\text{ mA}$	$r_f$		0.45	0.7	$\Omega$
	$f = 100\text{ MHz}$ , $I_F = 10\text{ mA}$	$r_f$		0.34	0.5	$\Omega$
Charge carrier life time	$I_F = 10\text{ mA}$ , $I_R = 6\text{ mA}$ , $i_R = 3\text{ mA}$	$t_{rr}$		90		ns

## Typical Characteristics ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

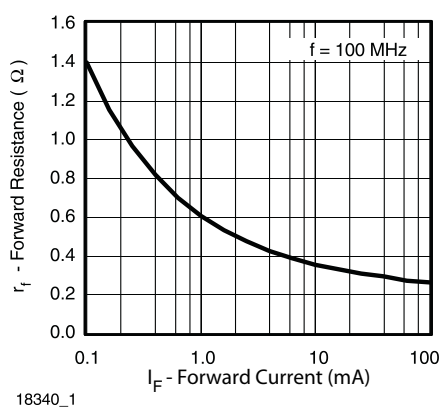


Figure 1. Forward Resistance vs. Forward Current

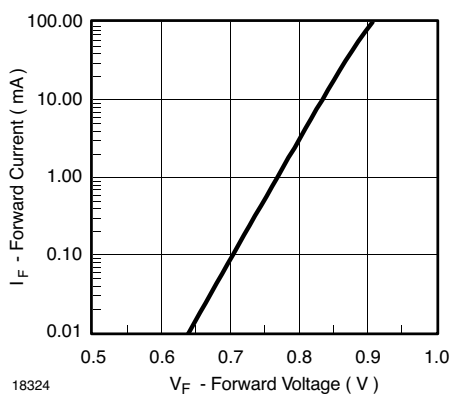


Figure 3. Forward Current vs. Forward Voltage

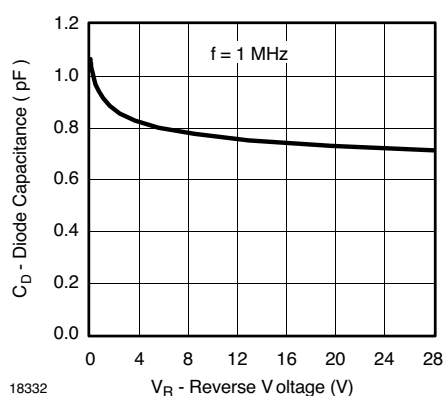


Figure 2. Diode Capacitance vs. Reverse Voltage

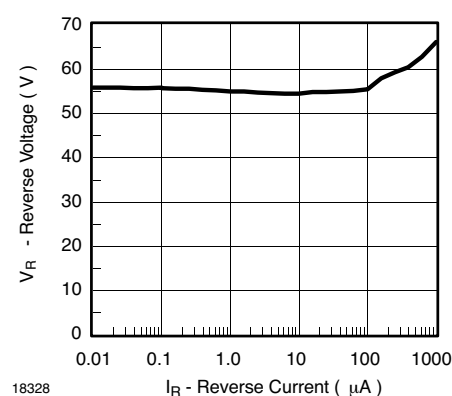


Figure 4. Reverse Voltage vs. Reverse Current

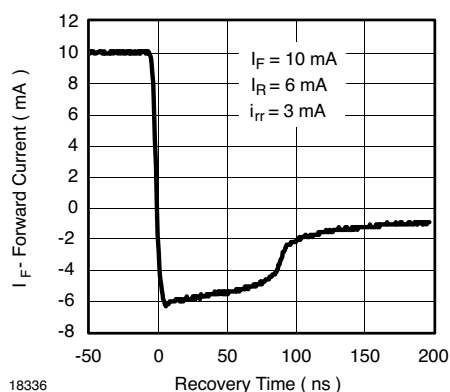
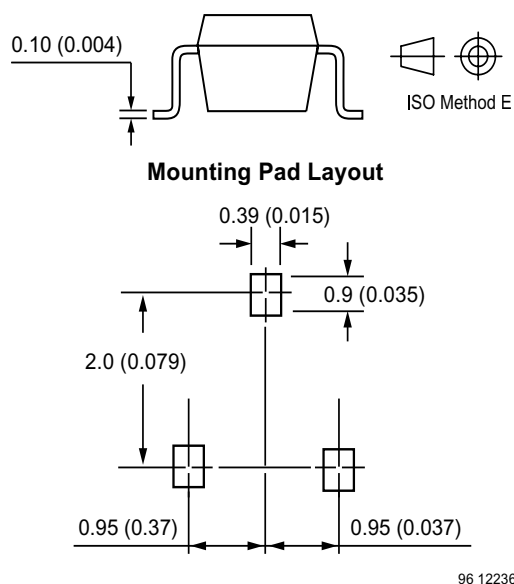
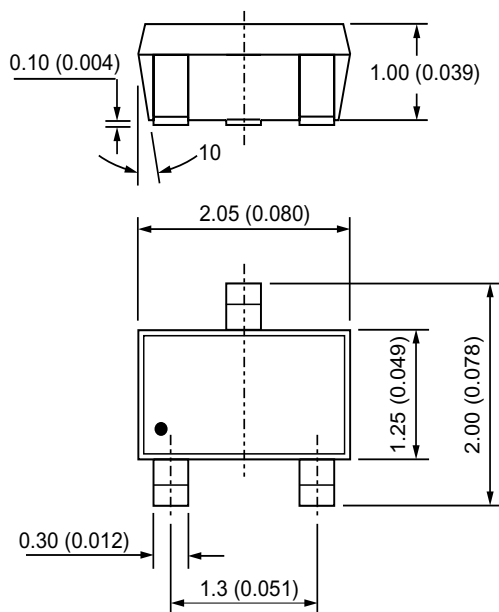


Figure 5. Typical Charge Recovery Curve

## Package Dimensions in mm (Inches)





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1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

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2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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